

5899 PENTODE

Five-Star Tube

★ ★ ★ ★

FOR RF AND IF AMPLIFIER APPLICATIONS

SEMI-REMOTE-CUTOFF 8-LEAD SUBMINIATURE SHOCK, VIBRATION RATINGS HEATER-CYCLING RATING

DESCRIPTION AND RATING=

The 5899 is a subminiature, semi-remote-cutoff pentode for use as a wideband, high-frequency amplifier. Its semi-remote-cutoff characteristic makes it suitable for use in circuits to which it is desired to apply automatic-gain-control.

The 5899 is a special-quality tube for use in critical industrial and military applications in which operational dependability is of primary importance. Features of the tube include a high degree of mechanical strength and a heater-cathode construction capable of withstanding many-thousand cycles of intermittent operation. When used in on-off control applications, the tube will maintain its emission capabilities after long periods of operation under cutoff conditions.

GENERAL

ELECTRICAL

Cathode—Coated Unipotential
Heater Voltage, AC or DC

Direct Interelectrode Capacitances

With Shield* Without Shield

Grid-Number 1 to Plate, maximum	015	0.03	$\mu\mu$ t
Input	4.2	4.0	$\mu\mu f$
Output	3.4	1.9	$\mu\mu$ f

^{*}With external shield of 0.405-inch inside diameter connected to cathode.

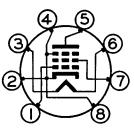
MECHANICAL

Mounting Position—Any
Envelope—T-3, Glass
Base—E8-10, Subminiature Button 8-Lead

GENERAL ELECTRIC

Supersedes ET-T1098 dated 8-54

BASING DIAGRAM



RETMA 8DL

TERMINAL CONNECTIONS

Lead 1-Grid Number 1

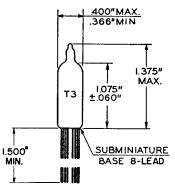
Lead 2—Cathode and Grid
Number 3

Lead 3—Heater
Lead 4—Cathode and Grid
Number 3

Lead 5—Plate
Lead 6—Heater
Lead 7—Grid Number 2
(Screen)

Lead 8—Cathode and Grid
Number 3

PHYSICAL DIMENSIONS



RETMA 3-1

12-56			
MAXIMUM RATINGS			
ABSOLUTE MAXIMUM VALUES			
Plate Voltage		165	Volts
Screen Voltage		155	Volts
Negative DC Grid-Number 1 Voltage			
Plate Dissipation		0 <i>.</i> 75	Watts
Screen Dissipation		0.35	Watts
DC Cathode Current		16 . 5	Milliamperes
Heater-Cathode Voltage Heater Positive with Respect to Cathode		200	M. II.
Heater Negative with Respect to Cathode			
· · · · · · · · · · · · · · · · · · ·			
Bulb Temperature at Hottest Point		220	C
CHARACTERISTICS AND TYPICAL OPERA	ATION		
Plate Voltage		100	Volte
Screen Voltage			
Cathode-Bias Resistor.			
Plate Resistance, approximate			
Transconductance			•
Plate Current			
Screen Current			•
Grid-Number 1 Voltage, approximate		2.0	miliamperes
G _m =25 Micromhos		14	Volts
CHARACTERISTICS LIMITS			
	Minimum	Maximu	m
Heater Current			
Ef = 6.3 voltsInitial	140	160	Milliamperes
Ef = 6.3 volts			
Ef = 6.3 volts	140 138	160 164	Milliamperes Milliamperes
Ef = 6.3 volts	140	160	Milliamperes
Ef = 6.3 volts	140 138	160 164	Milliamperes Milliamperes
$Ef = 6.3 \text{ volts}. \\ 500-Hr$ Plate Current $Ef = 6.3 \text{ volts}, Eb = 100 \text{ volts}, Ec2 = 100 \text{ volts}, Rk = 120 \text{ ohms (by-passed)}. Initial$	140 138	160 164	Milliamperes Milliamperes
Ef = 6.3 volts. Initial 500-Hr Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial	140 138 5.2	160 164 9.2	Milliamperes Milliamperes Milliamperes
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Ef = 6.3 volts. Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance (1) Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance Change with Heater Voltage Difference between Transconductance (1) and Transconductance at Ef =	140 138 5.2 1.0	160 164 9.2 3.0	Milliamperes Milliamperes Milliamperes Milliamperes
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Ef = 6.3 volts. Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance (1) Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance Change with Heater Voltage Difference between Transconductance (1) and Transconductance at Ef =	140 138 5.2 1.0	160 164 9.2 3.0	Milliamperes Milliamperes Milliamperes Milliamperes
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Ef = 6.3 volts. Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance (1) Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance Change with Heater Voltage Difference between Transconductance (1) and Transconductance at Ef = 5.7 volts (other conditions the same) expressed as a percentage of Transconductance (1). Initial 500-Hr Transconductance Change with Operation Difference between Transconductance (1) initially and after operation expressed as a percentage of initial value. . 500-Hr	140 138 5.2 1.0 3800	160 164 9.2 3.0 5200	Milliamperes Milliamperes Milliamperes Milliamperes Micromhos
Ef = 6.3 volts	140 138 5.2 1.0 3800	160 164 9.2 3.0 5200	Milliamperes Milliamperes Milliamperes Milliamperes Micromhos Percent Percent
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Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance (1) Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance Change with Heater Voltage Difference between Transconductance (1) and Transconductance at Ef = 5.7 volts (other conditions the same) expressed as a percentage of Transconductance (1)	140 138 5.2 1.0 3800	160 164 9.2 3.0 5200	Milliamperes Milliamperes Milliamperes Milliamperes Micromhos Percent Percent
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Ef = 6.3 volts. Plate Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Screen Current Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance (1) Ef = 6.3 volts, Eb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed). Initial Transconductance Change with Heater Voltage Difference between Transconductance (1) and Transconductance at Ef = 5.7 volts (other conditions the same) expressed as a percentage of Transconductance (1). Initial 500-Hr Transconductance Change with Operation Difference between Transconductance (1) initially and after operation expressed as a percentage of initial value. 500-Hr Average Transconductance Change with Operation Average of values for "Transconductance Change with Operation". 500-Hr	140 138 5.2 1.0 3800	160 164 9.2 3.0 5200 10 15	Milliamperes Milliamperes Milliamperes Milliamperes Micromhos Percent Percent Percent

CHARACTERISTICS LIMITS (Cont'd)

lataral astroda Compositarios		Minimum	Maximu	m
Interelectrode Capacitances Grid-Number 1 to Plate (g1 to p)	initial		0.015	μμf
Input (g1 to h, k, g2, g3)		3.8	4.8	μμ f
Output (p to h, k, g2, g3)	Initial	2.9	3.9	• • •
Measured with external shield of 0.405-inch diameter connected to cathod	de	2.7	3.7	μμf
Negative Grid-Number 1 Current				
Ef = 6.3 volts, $Eb = 100 volts$, $Ec2 = 100 volts$, $Rk = 120 ohms$ (by-passed)	,			
	Initial		0.3	Microamperes
•	500-Hr		0.8	Microamperes
the tar Called Labert Community				·
Heater-Cathode Leakage Current				
Ef = 6.3 volts, Ehk = 100 volts				
Heater Positive with Respect to Cathode			5.0	Microamperes
	500-Hr		10	Microamperes
Heater Negative with Respect to Cathode			5.0	Microamperes
	500-Hr		10	Microamperes
Interelectrode Leakage Resistance				
Ef = 6.3 volts. Polarity of applied d-c interelectrode voltage is such that	t			
no cathode emission results.				
Grid-Number 1 to All at 100 Volts DC	Initial	100		Megohms
Olid-Nollider File All di 100 Folis De	500-Hr	50		Megohms
Plate to All at 300 Volts DC		100		•
ridie to All di 300 volis DC	500-Hr	50		Megohms
	300-Hr	30		Megohms
Vibrational Noise Output Voltage, RMS				
Ef = 6.3 volts, Ebb = 100 volts, Ec2 = 100 volts, Rk = 120 ohms (by-passed))_			
$R_L = 10,000$ ohms, Vibrational acceleration = 15 G at 40 cps	Initial		60	Millivolts
• • • • • • • • • • • • • • • • • • • •				
Grid-Number 1 Emission Current				
Ef = 7.5 volts, Eb = 100 volts, Ec2 = 100 volts, Ecc1 = -14 volts, Rg1 = 1.0	0			
meg			0.5	Microamperes
			7.0	

The indicated 500-hour values are life-test end points for the following conditions of operation: Ef = 6.3 volts, Ef = 100 volts, Ef

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SPECIAL TESTS AND RATINGS

Stability Life Test

Statistical sample operated for one hour to evaluate and control initial variations in transconductance.

Survival Rate Life Test

Statistical sample operated for one hundred hours to evaluate and control early-life electrical and mechanical inoperatives.

Heater-Cycling Life Test

Statistical sample operated for 2000 cycles to evaluate and control heater-cathode defects. Conditions of test include Ef = 7.0 volts cycled for one minute on and four minutes off, Eb = Ec2 = Ec1 = 0 volts, and Ehk = 140 volts RMS.

Shock Rating-450 G

Statistical sample subjected to five impact accelerations of 450 G in each of four different positions. The accelerating forces are applied by the Navy-type, High Impact (flyweight) Shock Machine for Electronic Devices or its equivalent.

Fatique Rating—2.5 G

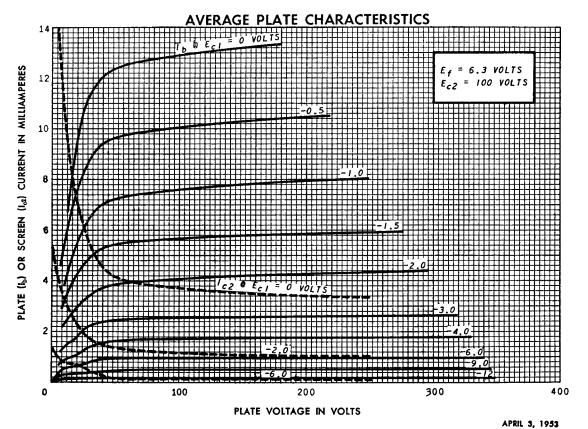
Statistical sample subjected to vibrational acceleration of 2.5 G for 32 hours minimum in each of three different positions. The sinusoidal vibration is applied at a fixed frequency between 25 and 60 cycles per second.

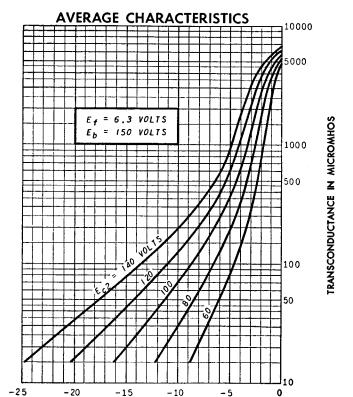
Altitude Rating-60,000 Feet

Statistical sample subjected to pressure of 55 millimeters of mercury to evaluate and control arcing and corona.

Note: The conditions for some of the indicated tests have deliberately been selected to aggravate tube failures for test and evaluation purposes. In no sense should these conditions be interpreted as suitable circuit operating conditions.

In the design of military equipment employing this tube, reference should be made to the appropriate MIL-E-1 specification.





GRID-NUMBER 1 VOLTAGE IN VOLTS

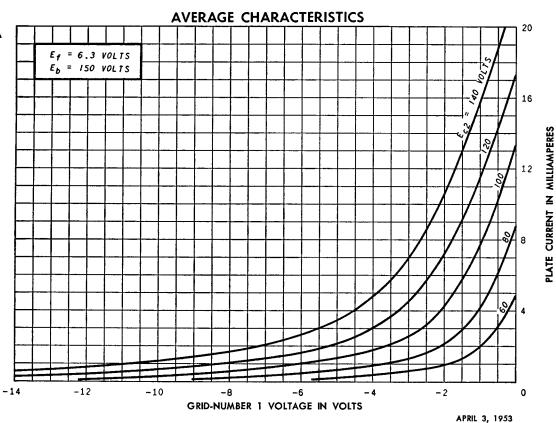
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AVERAGE CHARACTERISTICS

ELECTRONIC COMPONENTS DIVISION

GRID-NUMBER 1 VOLTAGE IN VOLTS

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APRIL 3, 1953